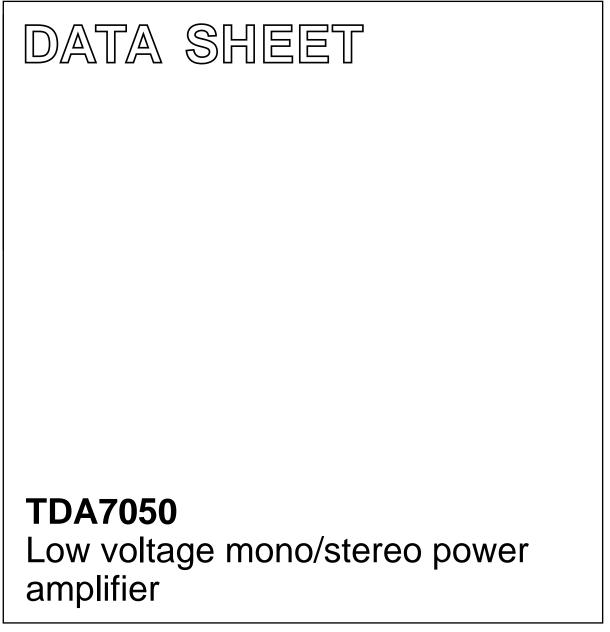
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INTEGRATED CIRCUITS



Product specification File under Integrated Circuits, IC01 June 1989

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Philips Semiconductors

Product specification

Low voltage mono/stereo power amplifier

TDA7050

GENERAL DESCRIPTION

The TDA7050 is a low voltage audio amplifier for small radios with headphones (such as watch, pen and pocket radios) in mono (bridge-tied load) or stereo applications.

Features

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- Limited to battery supply application only (typ. 3 and 4 V)
- Operates with supply voltage down to 1,6 V
- No external components required
- · Very low quiescent current
- Fixed integrated gain of 26 dB, floating differential input
- · Flexibility in use mono BTL as well as stereo
- Small dimension of encapsulation (see package design example)

QUICK REFERENCE DATA

Supply voltage range	V _P	1,6	to 6,0 V
Total quiescent current (at V _P = 3 V)	I _{tot}	typ.	3,2 mA
Bridge tied load application (BTL)			
Output power at $R_L = 32 \Omega$			
V _P = 3 V; d _{tot} = 10%	Po	typ.	140 mW
D.C. output offset voltage between the outputs	$ \Delta V $	max.	70 mV
Noise output voltage (r.m.s. value)			
at f = 1 kHz; $R_S = 5 k\Omega$	V _{no(rms)}	typ.	140 μV
Stereo application			
Output power at $R_L = 32 \Omega$			
d _{tot} = 10%; V _P = 3 V	Po	typ.	35 mW
d _{tot} = 10%; V _P = 4,5 V	Po	typ.	75 mW
Channel separation at $R_S = 0 \Omega$; f = 1 kHz	α	typ.	40 dB
Noise output voltage (r.m.s. value)			
at f = 1 kHz; $R_S = 5 k\Omega$	V _{no(rms)}	typ.	100 μV

PACKAGE OUTLINE

8-lead DIL; plastic (SOT97); SOT97-1; 1996 July 23.

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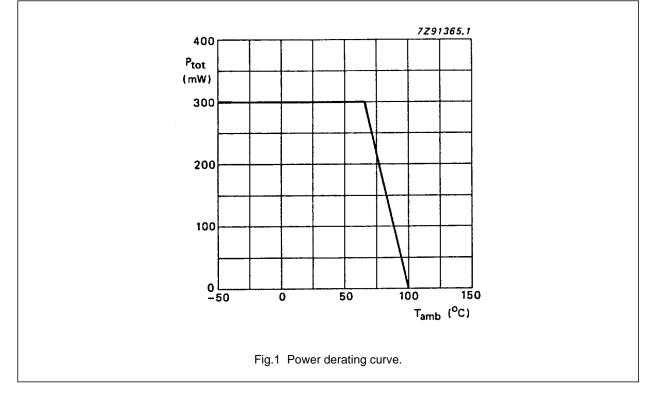
Philips Semiconductors

Product specification

Low voltage mono/stereo power amplifier

TDA7050

RATINGS Limiting values in accordance with the Absolute Maximum System (IEC 134)			
Supply voltage	VP	max.	6 V
Peak output current	I _{OM}	max.	150 mA
Total power dissipation	see deratir	ng curve F	ig.1
Storage temperature range	T _{stg}	–55 to	+ 150 °C
Crystal temperature	T _c	max.	100 °C
A.C. and d.c. short-circuit duration			
at $V_P = 3.0 V$ (during mishandling)	t _{sc}	max.	5 s



THERMAL RESISTANCE

From junction to ambient

R_{thj-a} = 110 K/W

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TDA7050

CHARACTERISTICS

 V_{P} = 3 V; f = 1 kHz; R_{L} = 32 $\Omega;$ T_{amb} = 25 °C; unless otherwise specified

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply					
Supply voltage	VP	1,6	-	6,0	V
Total quiescent current	I _{tot}	-	3,2	4	mA
Bridge-tied load application (BTL); see Fig.4					
Output power; note 1					
V _P = 3,0 V; d _{tot} = 10%	Po	-	140	-	mW
$V_{P} = 4,5 \text{ V}; \text{ d}_{tot} = 10\% \text{ (R}_{L} = 64 \Omega)$	Po	-	150	-	mW
Voltage gain	G _v	-	32	-	dB
Noise output voltage (r.m.s. value)					
$R_S = 5 \text{ k}\Omega; \text{ f} = 1 \text{ kHz}$	V _{no(rms)}	-	140	-	μV
$R_S = 0 \Omega$; f = 500 kHz; B = 5 kHz	V _{no(rms)}	-	tbf	-	μV
D.C. output offset voltage (at $R_S = 5 k\Omega$)	$ \Delta V $	-	-	70	mV
Input impedance (at $R_S = \infty$)	Z _i	1	-	-	MΩ
Input bias current	li	-	40	-	nA
Stereo application; see Fig.5					
Output power; note 1					
V _P = 3,0 V; d _{tot} = 10%	Po	-	35	-	mW
V _P = 4,5 V; d _{tot} = 10%	Po	-	75	-	mW
Voltage gain	G _v	24.5	26	27.5	dB
Noise output voltage (r.m.s. value)					
$R_S = 5 k\Omega; f = 1 kHz$	V _{no(rms)}	-	100	-	μV
$R_S = 0 \Omega$; f = 500 kHz; B = 5 kHz	V _{no(rms)}	-	tbf	-	μV
Channel separation					
$R_{S} = 0 \Omega; f = 1 \text{ kHz}$	α	30	40	-	dB
Input impedance (at $R_S = \infty$)	Z _i	2	-	-	MΩ
Input bias current	li	-	20	_	nA

Note

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1. Output power is measured directly at the output pins of the IC. It is shown as a function of the supply voltage in Fig.2 (BTL application) and Fig.3 (stereo application).

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Product specification

TDA7050

Low voltage mono/stereo power amplifier

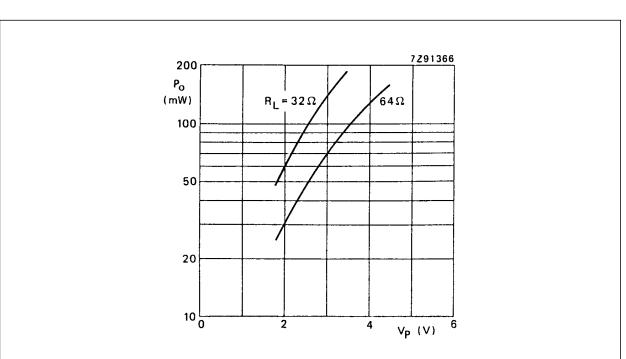
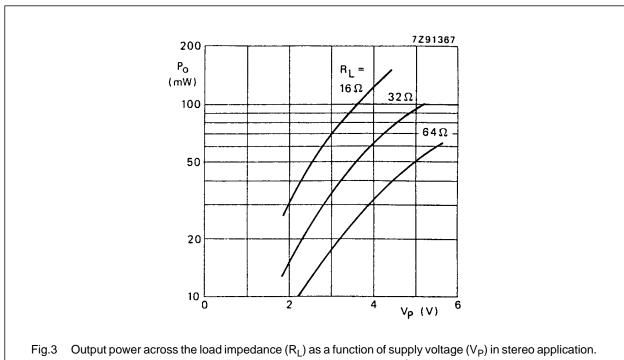


Fig.2 Output power across the load impedance (R_L) as a function of supply voltage (V_P) in BTL application. Measurements were made at f = 1 kHz; d_{tot} = 10%; T_{amb} = 25 °C.



Measurements were made at f = 1 kHz; d_{tot} = 10%; T_{amb} = 25 °C.

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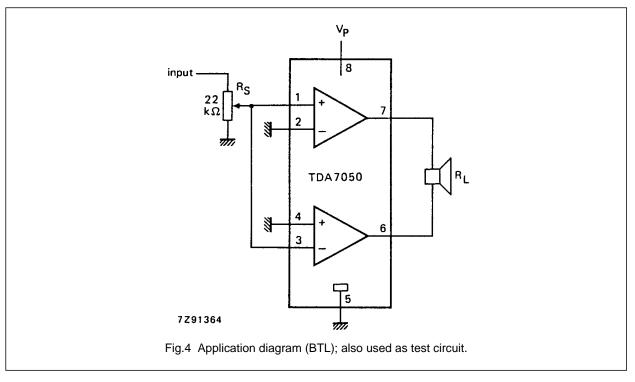
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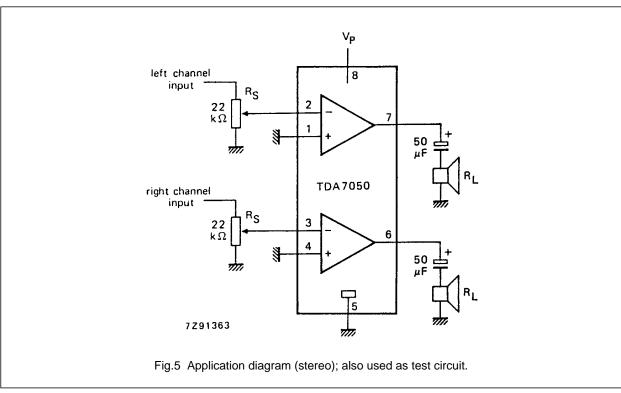
Product specification

TDA7050

Low voltage mono/stereo power amplifier

APPLICATION INFORMATION





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www.agelectronica.com

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Product specification

TDA7050

 M_E

(e1) M_H

SOT97-1

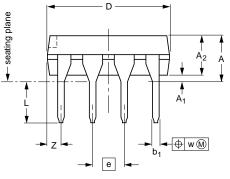
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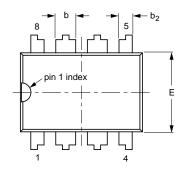
Philips Semiconductors

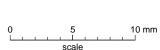
Low voltage mono/stereo power amplifier

PACKAGE OUTLINE

DIP8: plastic dual in-line package; 8 leads (300 mil)







DIMENSI	ONS (ind	ch dimer	nsions a	re derive	d from t	he origir	al mm d	imensio	ns)							
UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	с	D ⁽¹⁾	Е ⁽¹⁾	е	e ₁	L	M _E	м _н	w	
mm	4.2	0.51	3.2	1.73 1.14	0.53 0.38	1.07 0.89	0.36 0.23	9.8 9.2	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	
inches	0.17	0.020	0.13	0.068	0.021	0.042	0.014	0.39	0.26	0.10	0.30	0.14	0.32	0.39	0.01	Γ

Note

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1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

0.045

0.015

0.035

0.009

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT97-1	050G01	MO-001AN				92-11-17 95-02-04

0.36

0.24

0.12

0.31

0.33

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Z⁽¹⁾

max.

1.15

0.045

Product specification

Low voltage mono/stereo power amplifier

TDA7050

SOLDERING

Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"IC Package Databook"* (order code 9398 652 90011).

Soldering by dipping or by wave

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ($T_{stg max}$). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

Repairing soldered joints

Apply a low voltage soldering iron (less than 24 V) to the lead(s) of the package, below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than 300 °C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 °C, contact may be up to 5 seconds.

DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.